

## PMEG2005ELD

# 20 V, 0.5 A low V<sub>F</sub> MEGA Schottky barrier rectifier

Rev. 1 — 4 May 2011

**Product data sheet** 

### 1. Product profile

#### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD882D leadless ultra small Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

#### 1.2 Features and benefits

Forward current: I<sub>F</sub> ≤ 0.5 A

Reverse voltage: V<sub>R</sub> ≤ 20 V

Low forward voltage: V<sub>F</sub> ≤ 500 mV

Low reverse current

- AEC-Q101 qualified
- Solderable side pads
- Package height typ. 0.37 mm
- Ultra small and leadless SMD plastic package

#### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications
- Ultra high-speed switching

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F(AV)</sub> average forward		square wave; $\delta$ = 0.5; f = 20 kHz				
current	current	T <sub>amb</sub> ≤ 85 °C	[1] -	-	0.5	Α
		T <sub>sp</sub> ≤ 130 °C	-	-	0.5	Α
I <sub>R</sub>	reverse current	V <sub>R</sub> = 10 V	-	5	30	μΑ
$V_R$	reverse voltage		-	-	20	V
$V_{F}$	forward voltage	I <sub>F</sub> = 500 mA	[2] _	450	500	mV

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.



<sup>[2]</sup> Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02.$ 

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode	[1]	. 54
2	anode	1 2	1 <del>    2</del> sym001
		Transparent top view	

<sup>[1]</sup> The marking bar indicates the cathode.

## 3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PMEG2005ELD	-	leadless ultra small plastic package; 2 terminals; body 1 $\times$ 0.6 $\times$ 0.4 mm	SOD882D		

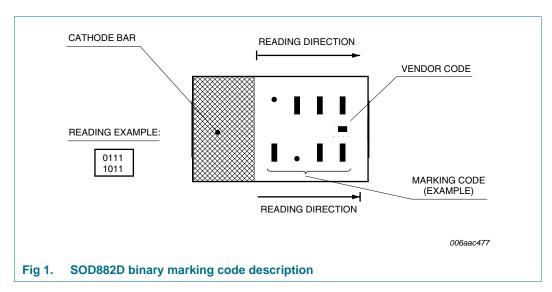
### 4. Marking

Table 4. Marking codes

3	
Type number	Marking code <sup>[1]</sup>
PMEG2005ELD	0101 0000

<sup>[1]</sup> For SOD882D binary marking code description, see Figure 1.

#### 4.1 Binary marking code description



## 5. Limiting values

**Table 5.** Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	20	V
I <sub>F(AV)</sub>	average forward current	square wave; $\delta$ = 0.5; f = 20 kHz			
		$T_{amb} \le 85  ^{\circ}C$	<u>[1]</u> -	0.5	Α
		T <sub>sp</sub> ≤ 130 °C	-	0.5	Α
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq \text{1 ms; } \delta \leq \text{0.25}$	-	2.5	A
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; $t_p = 8 \text{ ms}$	[2]	3	Α
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	[3] _	340	mW
			<u>[1]</u> _	660	mW
			[4]	1000	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[2]</sup>  $T_i = 25$  °C prior to surge.

<sup>[3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[4]</sup> Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

#### 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	-	370	K/W
			[1][3]	-	-	190	K/W
			[1][4]	-	-	125	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		<u>[5]</u>	-	-	50	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.
- [4] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.
- [5] Soldering point of cathode tab.

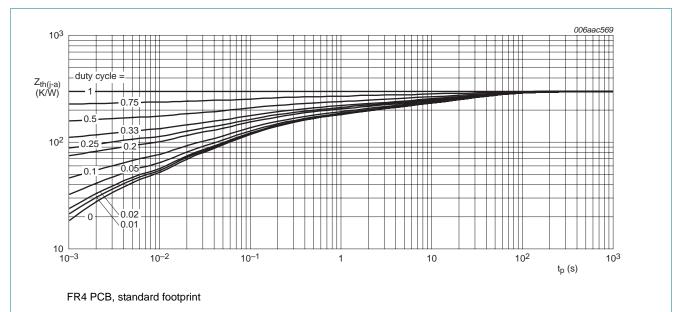


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

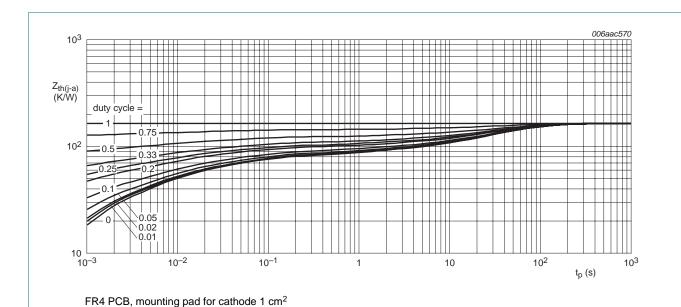


Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

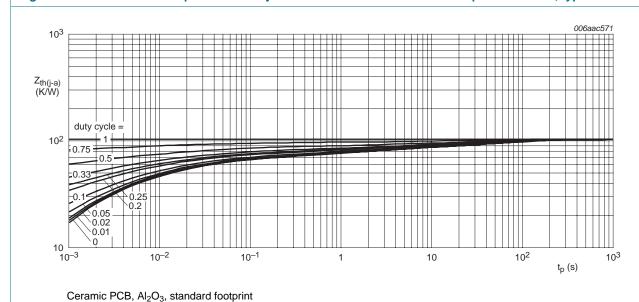


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

#### 7. Characteristics

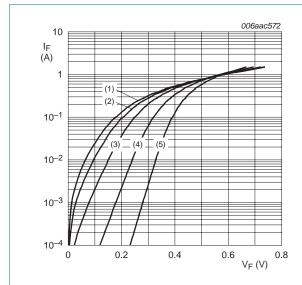
Table 7. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage		<u>[1]</u>			
		$I_F = 0.1 \text{ mA}$	-	115	180	mV
		$I_F = 1 \text{ mA}$	-	175	240	mV
		I <sub>F</sub> = 10 mA	-	240	290	mV
		I <sub>F</sub> = 100 mA	-	320	380	mV
		I <sub>F</sub> = 500 mA	-	450	500	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 10 V	-	5	30	μΑ
C <sub>d</sub>	diode capacitance	$V_R = 1 V$ ; $f = 1 MHz$	-	24	30	pF
t <sub>rr</sub>	reverse recovery time		[2] _	7	-	ns

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02.$ 

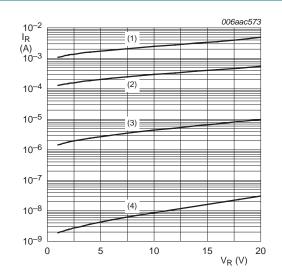
<sup>[2]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 1 mA.





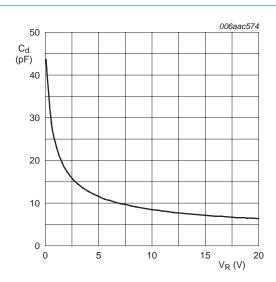
- (2)  $T_i = 125 \, ^{\circ}C$
- (3)  $T_i = 85 \,^{\circ}\text{C}$
- (4) T<sub>j</sub> = 25 °C
- (5)  $T_i = -40 \, ^{\circ}C$

Fig 5. Forward current as a function of forward voltage; typical values



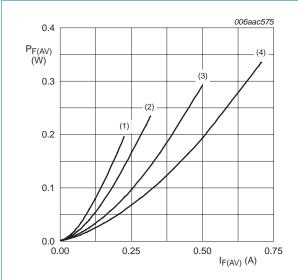
- (1)  $T_i = 125 \,^{\circ}\text{C}$
- (2)  $T_i = 85 \, ^{\circ}C$
- (3)  $T_i = 25 \,^{\circ}\text{C}$
- (4)  $T_j = -40 \, ^{\circ}C$

Fig 6. Reverse current as a function of reverse voltage; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$ 

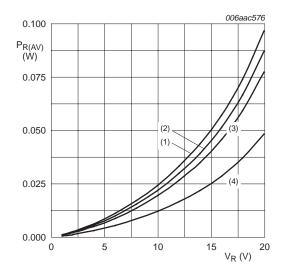
Fig 7. Diode capacitance as a function of reverse voltage; typical values



T<sub>i</sub> = 150 °C

- (1)  $\delta = 0.1$
- (2)  $\delta = 0.2$
- (3)  $\delta = 0.5$
- (4)  $\delta = 1$

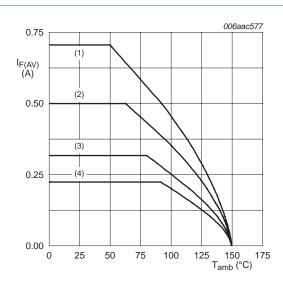
Fig 8. Average forward power dissipation as a function of average forward current; typical values



T<sub>j</sub> = 125 °C

- (1)  $\delta = 1$
- (2)  $\delta = 0.9$
- (3)  $\delta = 0.8$
- (4)  $\delta = 0.5$

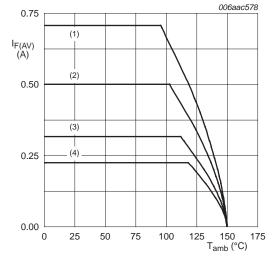
Fig 9. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ; f = 20 kHz
- (3)  $\delta = 0.2$ ; f = 20 kHz
- (4)  $\delta = 0.1$ ; f = 20 kHz

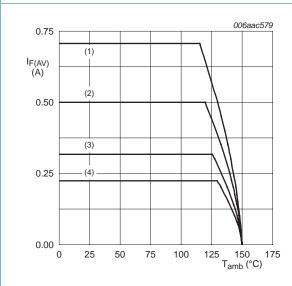
Fig 10. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1  $\mbox{cm}^2$ 

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ; f = 20 kHz
- (3)  $\delta = 0.2$ ; f = 20 kHz
- (4)  $\delta = 0.1$ ; f = 20 kHz

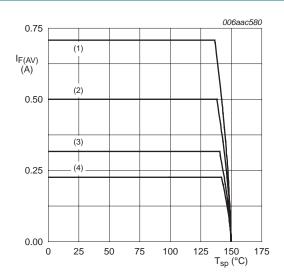
Fig 11. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ; f = 20 kHz
- (3)  $\delta = 0.2$ ; f = 20 kHz
- (4)  $\delta = 0.1$ ; f = 20 kHz

Fig 12. Average forward current as a function of ambient temperature; typical values



T<sub>i</sub> = 150 °C

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ; f = 20 kHz
- (3)  $\delta = 0.2$ ; f = 20 kHz
- (4)  $\delta = 0.1$ ; f = 20 kHz

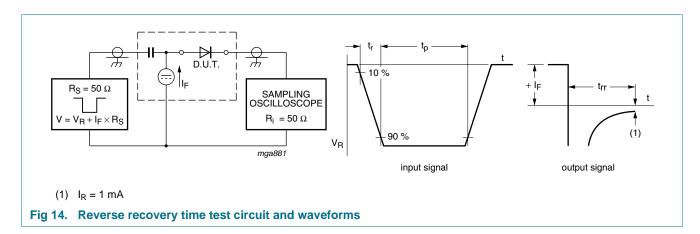
Fig 13. Average forward current as a function of solder point temperature; typical values

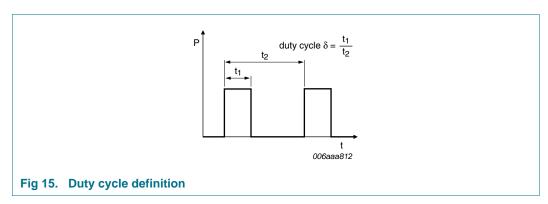
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#### 8. Test information



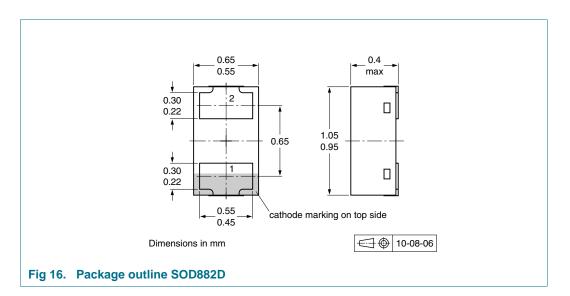


The current ratings for the typical waveforms as shown in <u>Figure 10</u>, <u>11</u>, <u>12</u> and <u>13</u> are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



## 10. Packing information

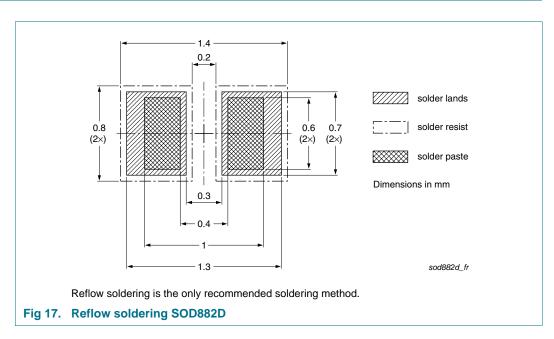
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	/
			10000	
PMEG2005ELD	SOD882D	2 mm pitch, 8 mm tape and reel	-315	

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

### 11. Soldering



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## 12. Revision history

#### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG2005ELD v.1	20110504	Product data sheet	-	-

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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## PMEG2005ELD

### 20 V, 0.5 A low V<sub>F</sub> MEGA Schottky barrier rectifier

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